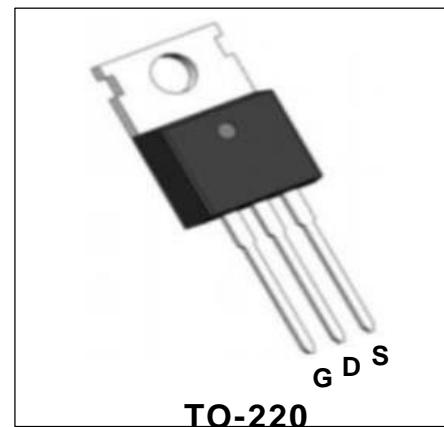


## Description

WMK161N15T2 uses advanced power trench technology that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.



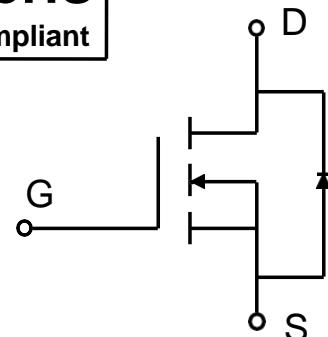
## Features

- $V_{DS} = 150V$ ,  $I_D = 161A$ ,  $R_{DS(on)} < 6 m\Omega$  @  $V_{GS} = 10V$
- High Speed Power Switching
- Low  $R_{DS(ON)}$
- Low Gate Charge
- 100% EAS Guaranteed



## Applications

- Synchronous Rectification in SMPS
- Hard Switching and High Speed Circuit
- UPS



## Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source voltage	$V_{DS}$	150	V
Gate-Source voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$I_D$	161	A
$T_C=100^\circ C$		115	
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	540	A
Single Pulse Avalanche Energy <sup>3</sup>	$E_{AS}$	720	mJ
Total Power Dissipation <sup>4</sup>	$P_D$	360	W
Operating Junction and Storage Temperature Range	$T_J$ , $T_{STG}$	-55 to 175	°C

## Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction-to-Ambient <sup>1</sup>	$R_{\theta JA}$	61	°C/W
Thermal Resistance from Junction-to-Case <sup>1</sup>	$R_{\theta JC}$	0.4	°C/W



# WMK161N15T2

## Electrical Characteristics $T_c = 25^\circ\text{C}$ , unless otherwise noted

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	150	-	-	V
Gate-body Leakage current	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	$\pm 100$	nA
Zero Gate Voltage Drain Current $T_J=25^\circ\text{C}$	$I_{DSS}$	$V_{DS} = 150V, V_{GS} = 0V$	-	-	1	$\mu\text{A}$
			-	-	100	
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	2	3	4	V
Drain-Source On-Resistance <sup>2</sup>	$R_{DS(\text{on})}$	$V_{GS} = 10V, I_D = 20A$	-	5.4	6	$\text{m}\Omega$
Transconductance	$g_{fs}$	$V_{DS}=5V, I_D=20A$	-	80	-	S
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 75V, V_{GS} = 0V, f = 1\text{MHz}$	-	6220	-	pF
Output Capacitance	$C_{oss}$		-	480	-	
Reverse Transfer Capacitance	$C_{rss}$		-	11	-	
<b>Switching Characteristics</b>						
Gate Resistance	$R_g$	$V_{GS} = 0V, V_{DS} = 0V, f = 1\text{MHz}$	-	2.7	-	$\Omega$
Total Gate Charge	$Q_g$	$V_{GS} = 10V, V_{DD} = 75V, I_D = 20A$	-	78	-	nC
Gate-Source Charge	$Q_{gs}$		-	29	-	
Gate-Drain Charge	$Q_{gd}$		-	11	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10V, V_{DD} = 75V, R_G = 10\Omega, I_D = 20A$	-	26	-	nS
Rise Time	$t_r$		-	19	-	
Turn-Off Delay Time	$t_{d(off)}$		-	39	-	
Fall Time	$t_f$		-	15	-	
<b>Drain-source body diode Characteristics</b>						
Diode Forward Voltage <sup>2</sup>	$V_{SD}$	$I_S = 20A, V_{GS} = 0V$	-	0.9	1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$V_R = 75V, I_F = 20A, dI/dt = 100A/\mu\text{s}$	-	80	-	nS
Body Diode Reverse Recovery Charge	$Q_{rr}$		-	160	-	nC

### Notes:

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width  $\leq 300\mu\text{s}$  , duty cycle  $\leq 2\%$
3. The EAS data shows Max. rating . The test condition is  $V_{DD}=25V, V_{GS}=10V, L=0.4\text{mH}, I_{AS}=60A$
4. The power dissipation is limited by  $175^\circ\text{C}$  junction temperature

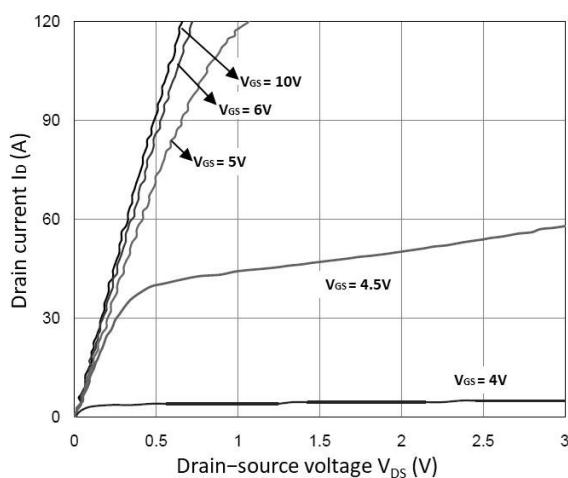


Figure 1. Output Characteristics

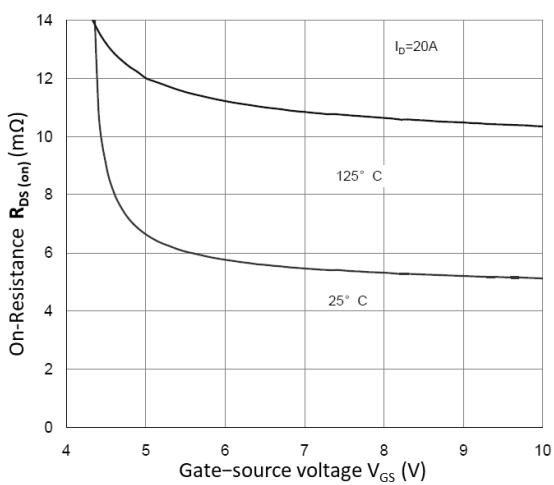


Figure 2.  $R_{DS(on)}$  vs.  $V_{GS}$

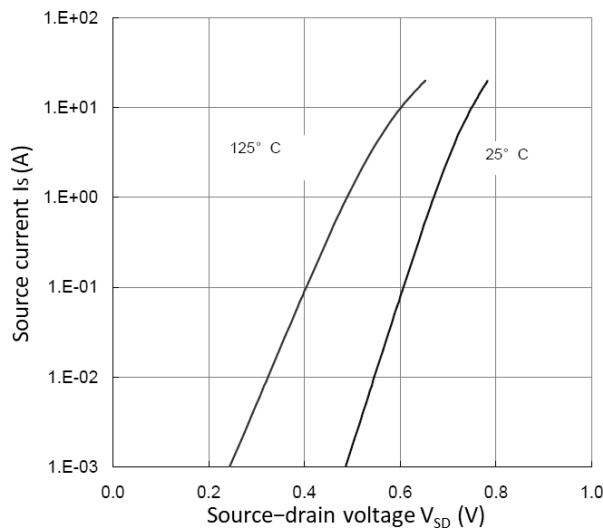


Figure 3. Forward Characteristics of Reverse

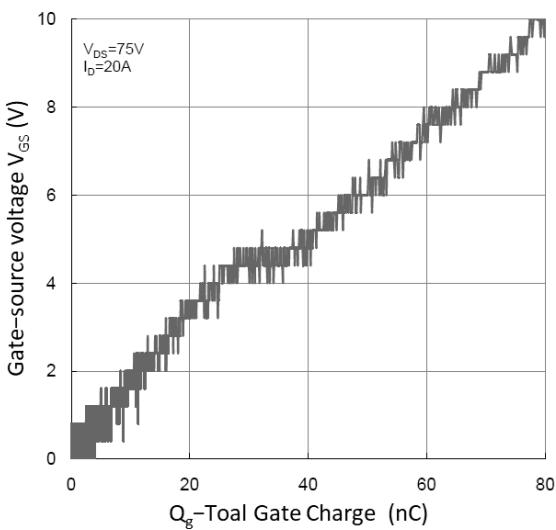


Figure 4. Gate Charge Characteristics

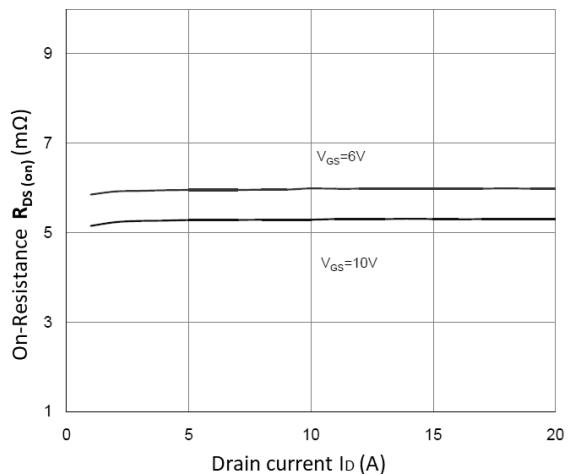


Figure 5.  $R_{DS(ON)}$  vs.  $I_D$

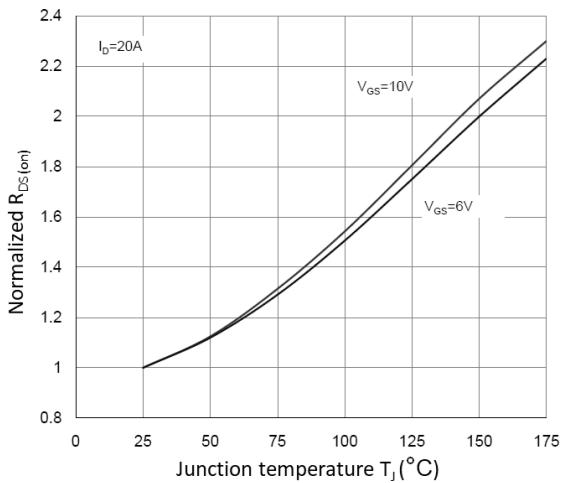


Figure 6. Normalized  $R_{DS(on)}$  vs.  $T_J$

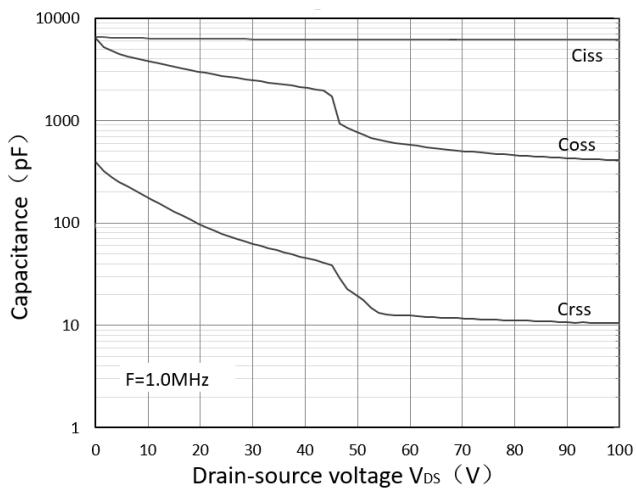


Figure 7. Capacitance Characteristics

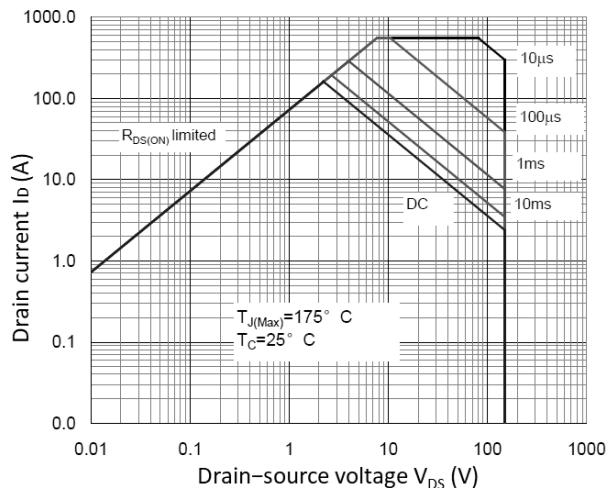


Figure 8. Safe Operating Area

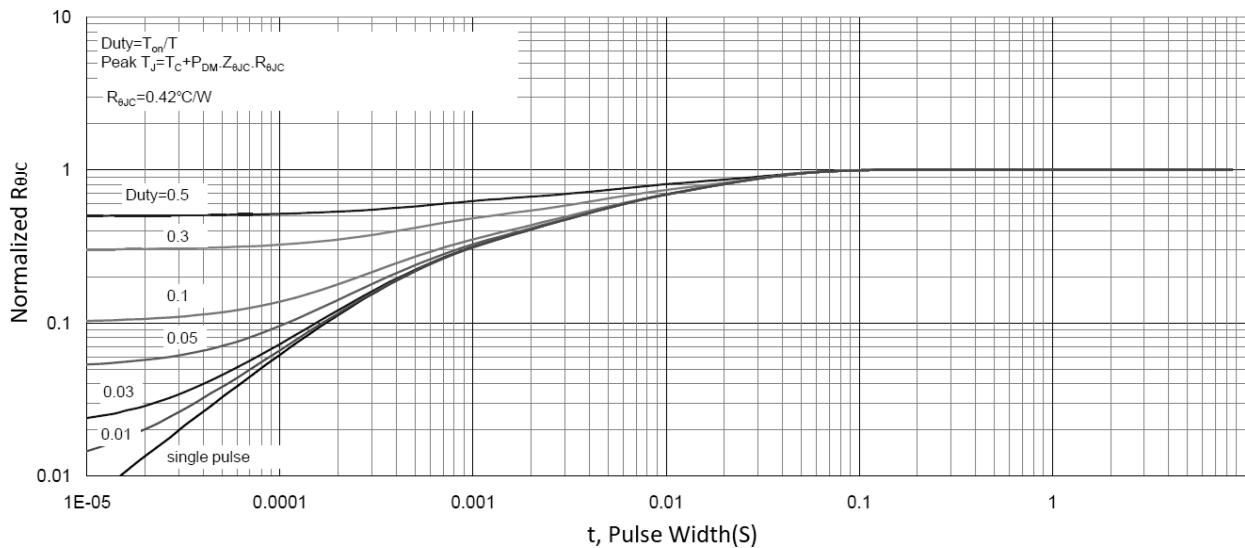


Figure 9. Normalized Maximum Transient Thermal Impedance

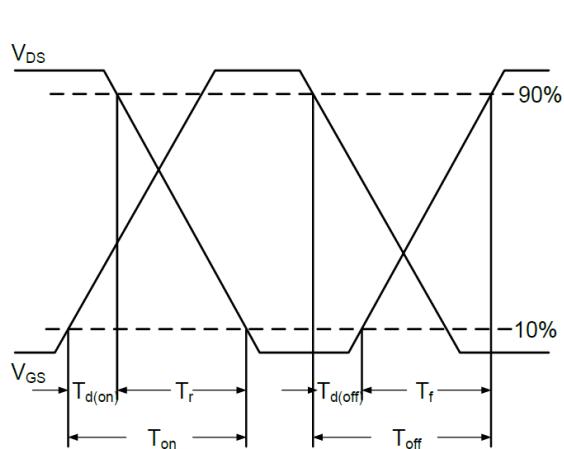


Figure 10. Switching Time Waveform

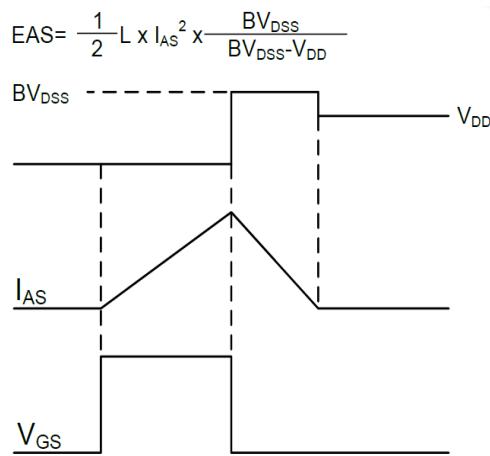
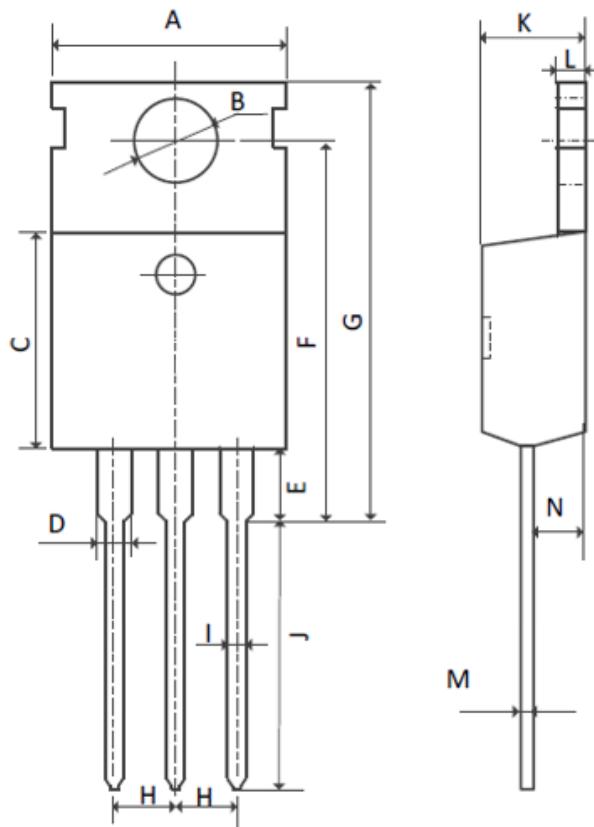


Figure 11. Unclamped Inductive Switching

## Mechanical Dimensions for TO-220



## COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	9.70	10.30
B	3.40	3.80
C	8.80	9.40
D	1.17	1.47
E	2.60	3.40
F	15.10	16.70
G	19.55MAX	
H	2.54REF	
I	0.70	0.95
J	9.35	11.00
K	4.30	4.77
L	1.20	1.45
M	0.40	0.65
N	2.20	2.60